A Cellular-Space-Division-Based Method of Moments Algorithm for the Pattern Analysis of Printed-Circuit Radiators

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Abstract—A cellular-space-division-based method of moments (MoM) algorithm for the analysis of geometries involving imperfectly conducting planar radiators as well as lossy and finite-extent dielectric substrates is presented. Since the technique—via the volume equivalence theorem—replaces the structure under analysis with an equivalent structure composed of thin-wall cells, modeling of the surrounding environment is not required, hence, completely avoiding the need for absorbing boundary conditions. Real (as opposed to perfect) material parameters are incorporated via properly defined surface impedances. Several examples of radiation patterns (including radiation underneath the ground plane of a finite-extent substrate) of planar geometries are presented. The calculated patterns are compared with measured results and are found to be in good agreement.

Index Terms—Method of moments, microstrip antennas.

I. INTRODUCTION

MODERN planar antenna designs rely heavily on accurate and reliable analysis software. Whereas increasing complexity of printed-circuit radiators demands a high flexibility from the underlying modeling tool, individual numerical techniques are often too restricted in their applications or too CPU time and memory intensive to allow an individual analysis or design to be completed in a timely fashion. Desirable features of suitable numerical models include:

1) the capability of analyzing multilayered circuitry consisting of feed lines, apertures, radiator, and dielectric overlays (e.g., [1]);
2) the incorporation of dielectric and conductor losses (e.g., [2]);
3) the possibility of including finite-size and piecewise homogeneous dielectrics (e.g., [3]);
4) the limitation of the extent of a ground plane (e.g., [4]);
5) the concentration of the numerical attention exclusively on the circuit (e.g., [5]) without the need for modeling the (free-space) environment and without any absorbing boundary conditions.

Therefore, this paper focuses on a cellular-space-division-based method of moments (MoM) algorithm, which includes all the five features listed above. The method is primarily based on earlier work by Rubin and Dajjavad [5]. However, we have made the method systematic by replacing the numerical integration procedure (which is the heart of the technique) with an exact, robust, and efficient algorithm [6], [7]. Moreover, we have implemented suggestions in [5] to incorporate conductor and substrate losses, which, nowadays, are considered a prerequisite for any meaningful printed-circuit analysis.

The fundamental steps are outlined in Section II below and include some modifications with respect to [5]. Section III details the numerical refinements for the implementation of the code. The results in Section IV focus on radiation patterns of planar antenna configurations for four types of feeding mechanisms. Results in terms of input impedance and input reflection coefficient for planar geometries are presented in [7] and [8] and need not be repeated here.

II. THEORY

Fig. 1 illustrates the subdivision of a planar microwave circuit into a cellular structure. Each of the \( N_x \cdot N_y \cdot N_z \) thin-wall sections is associated with a series of full rooftop current functions, a full rooftop being composed of a rising half rooftop and a falling half rooftop [Fig. 2(a), (b)] [5]. For a
single cell where \(N_x = N_y = N_z = 1\), the number of currents required is 12, but in practical applications the attachments to neighbor cells reduce the average number of currents (full rooftops) per cell \(P_{sv}\) to
\[
P_{sv} = 9 + 2 \left( \frac{1}{N_x} + \frac{1}{N_y} + \frac{1}{N_z} \right) - \left( \frac{1}{N_x N_y} + \frac{1}{N_y N_z} + \frac{1}{N_z N_x} \right)
\]
\[\text{(1)}\]
e.g., the fourth current in Fig. 2(c) is linearly dependent and, therefore, not shown. Although the number in (1) is larger than that of, e.g., a finite-difference analysis, it is noteworthy that the computational space is smaller, as we need not model the surrounding environment.

Material properties are incorporated through the cell’s total impedances, e.g., \(R_x\) in the \(x\) direction. For the thin-wall structure, however, the surface impedance must be such that when multiplied by length \(\tau_x\) and divided by perimeter \(2(\tau_y + \tau_z)\), the result is again \(R_x\). Thus, the surface impedance along \(x\)—\(R_{sx}\) (Fig. 3)—is given by
\[
R_{sx} = \frac{R_x}{2(\tau_y + \tau_z)} \frac{(1}{\tau_y} + \frac{1}{\tau_z})}{\omega \epsilon_r (\epsilon_r - 1)} \quad \text{[\Omega]} \quad \text{(2)}
\]
where expressions
\[
\epsilon = \epsilon' - j \epsilon'' = \epsilon_0 \epsilon_r - j \frac{\sigma_d}{\omega} \quad \text{[F/m]}
\]
\[
R_{sx,y,z} = \frac{1 + j}{\delta \sigma_m} \quad \text{[\Omega]} \quad \text{(3)}
\]
are used for imperfect dielectrics and conductors, respectively. \(\sigma_d\) is the conductivity of the dielectric, \(\sigma_m\) the conductivity of the metallization and \(\delta\) is the penetration depth. Note that the permittivity in (2), utilizing the volume equivalence theorem [9], is defined with respect to the surrounding free-space environment.

The electric field boundary condition applied over each dielectric cell wall and conductor surface is
\[
E_{t}^{\text{inc}} - J_S R_S = -E_{t}^{\text{inc}} \quad \text{[V/m]} \quad \text{(4)}
\]
where the incident field \(E_{t}^{\text{inc}}\) is related to the applied voltage \(V_\beta\) by [5]
\[
V_\beta = -\int_{u_{1\alpha}}^{u_{2\alpha}} E_{t}^{\text{inc}}(x,y,z) \cdot e_{u\beta} \, du \quad \text{[V]} \quad \text{(5)}
\]
and the volume current density \(J\) may be compactly expressed as
\[
J = \sum_{\alpha=1}^{P} R_\alpha(x,y,z) \mathbf{I}_\alpha \mathbf{e}_{u\alpha} \quad \text{[A/m\(^2\)].} \quad \text{(6)}
\]
In (6), \(I_\alpha\) [A/m] is the current coefficient, \(P\) is the total number of rooftop functions, and
\[
R_\alpha(x,y,z) = q_{rwa}(u - u_\alpha)p_{rwa}(v - v_\alpha)\delta(w - w_\alpha) \quad \text{[\Omega]} \quad \text{(7)}
\]
is the rooftop function centered at \(x = x_\alpha, y = y_\alpha, z = z_\alpha\), where \(q_{r}(u)\) is the triangle function defined as
\[
q_{r}(u) = \begin{cases} 1 & -\tau \leq u \leq \tau \\ 0 & \text{elsewhere,} \end{cases} \quad \text{(8)}
\]
\(p_{r}(v)\) is the pulse function defined as
\[
p_{r}(v) = \begin{cases} 1 & -\tau/2 \leq v \leq \tau/2 \\ 0 & \text{elsewhere,} \end{cases} \quad \text{(9)}
\]
and \(\delta(w)\) [\$/m] is the Dirac delta function. Moreover, variables \(u, v, \tau_\alpha, v_\alpha, \text{and } w_\alpha\) have been defined in terms of \(x, y, \text{and } z\) (c.f., Fig. 3) as [5]
\[
u = e_{u\alpha} \cdot (xe_x + ye_y + ze_z)
\]
\[
v = e_{v\alpha} \cdot (xe_x + ye_y + ze_z)
\]
\[
w = e_{w\alpha} \cdot (xe_x + ye_y + ze_z)
\]
\[
\tau_{u\alpha} = e_{u\alpha} \cdot (\tau_x e_x + \tau_y e_y + \tau_z e_z)
\]
\[
\tau_{v\alpha} = e_{u\alpha} \cdot (\tau_x e_x + \tau_y e_y + \tau_z e_z)
\]
\[
\tau_{w\alpha} = e_{u\alpha} \cdot (\tau_x e_x + \tau_y e_y + \tau_z e_z)
\]
\[\text{(10)}\]
where \(e_x, e_y, \text{and } e_z\) are the unit vectors along the \(x, y, \text{and } z\) direction, respectively; \(e_{u\alpha}\) is along the direction of current flow, \(e_{w\alpha}\) is normal to the plane containing the rooftop, and \(e_{v\alpha}\) is orthogonal to both \(e_{u\alpha}\) and \(e_{w\alpha}\).

Associated with each rooftop \(\alpha\) is a line interval or integration path (Fig. 1) over which the electric field is tested. This interval is defined by its end points located at \((u_{1\alpha}, \tau_{v\alpha}, w_{\alpha})\) and \((u_{2\alpha}, \tau_{v\alpha}, w_{\alpha})\), where
\[
u_{1\alpha} = u_\alpha - \tau_{v\alpha}/2
\]
\[
u_{2\alpha} = u_\alpha + \tau_{v\alpha}/2
\]
\[\text{(11)}\]
e.g., for a rooftop that lies in the y-z plane and has current directed along the y direction $R_\gamma (x, y, z) = \delta(x-x_0)q_{\gamma \alpha}(y-y_0)pr_{\gamma}(z-z_0)$ and $u_{\alpha 0} = y_\alpha - r_\gamma/2$ and $u_{\alpha 0} = y_\alpha + r_\gamma/2$.

With this in mind, we introduce the following integrals:

$$F_A = \int \int q_{\tau \alpha}(u' - u_\alpha)pr_{\tau}(v' - v_\alpha)$$
$$= \frac{e^{-jkr(u-u',v-v',w-w_{\alpha})}}{r(u-u',v-v',w-w_{\alpha})}du'dv' \text{[m]}$$

(12)

$$F_{Sf} = \frac{1}{\tau_{\alpha \alpha}} \int \int pr_{\tau}(u' - u_\alpha + \frac{\tau_{\alpha \alpha}}{2})pr_{\tau}(v' - v_\alpha)$$
$$= \frac{e^{-jkr(u-u',v-v',w-w_{\alpha})}}{r(u-u',v-v',w-w_{\alpha})}du'dv'$$

(13)

where $f/r$ denotes the falling/rising half rooftop.

Since the scattered field can be written as $E_{\text{scatt}} = -j\omega A - \nabla \phi$ and since the total vector and scalar potentials are given by

$$A = \frac{\mu_0}{4\pi} \sum_{\alpha=1}^{P} I_{\alpha} e_{\alpha} F_A$$

(14)

$$\Phi = \frac{1}{j4\pi \omega \mu_0} \sum_{\alpha=1}^{P} I_{\alpha} (F_{Sf} - F_{Sf}')$$

(15)

the individual entries $Z_{\beta \alpha}$ of the impedance matrix used in the MoM formulation are obtained as

$$Z_{\beta \alpha} = -\int_{\gamma_1}^{\gamma_2} \left[ \frac{1}{4\pi} \left( j\omega \mu_0 \int F_A e_{\alpha} + \frac{1}{j\omega \epsilon_0} \nabla (F_{Sf} - F_{Sf}') \right) \right.$$
$$+ \frac{\tau_{\alpha \alpha}}{2(\tau_{\alpha \alpha} + \tau_{\alpha \alpha}')} R_{\alpha \alpha}'(x,y,z) e_{\alpha} \bigg]$$
$$\cdot e_{\beta} \text{ du} \text{ [m]}$$

(16)

where

$$R_{\alpha}(x,y,z) = \begin{cases} q_{\tau \alpha}(u - u_\alpha)pr_{\tau}(v - v_\alpha), & w = w_{\alpha}, \\ 0, & w \neq w_{\alpha}. \end{cases}$$

(17)

For a given voltage excitation vector, the coefficients $I_{\alpha}$ [A/m] of the equivalent surface currents, as dictated by the volume equivalence theorem, are obtained by inverting the impedance matrix. Since a numerically stable integration procedure is used [7], the entries of the impedance matrix are well defined, and so are the individual currents. Circuit responses and radiation characteristics are then calculated from the currents. For all structures analyzed so far, convergence is reached with 12–20 cells per guided wavelength ($\lambda_g$) in case of scattering parameter and input impedance analysis, while 8–12 cells/$\lambda_g$ suffice for radiation characteristics.

### III. Numerical Refinements

For all self impedances and some mutual impedances, the integrals of (12) and (13) contain singularities. Although integrations over rectangular regions are required, in both cases we perform a transformation to the polar coordinate system. This eliminates the singularities in the generalized two-dimensional exponential integrals and an exact and stable solution free of any “numerical tuning” is obtained. For details of this procedure, the reader is referred to [6] and [7].

For the pairs of $I_{\alpha}$ (source) and $V_{\beta}$ (target) that are distant from each other, [5] employs the point-source approximation in the evaluation of (12) and (13) of the corresponding $Z_{\beta \alpha}$’s. Evaluating the $Z_{\beta \alpha}$’s for short source-target distances exactly, we have assessed that the point-source approximation unnecessarily compromises accuracy of the calculations for a given discretization and, therefore, avoided the approximation completely. Instead, we have employed the algorithm described below.

The algorithm is based on the following rationale. Clearly, numerical evaluation of $F_A$ and $F_S$, which are defined in (12) and (13), is the most important factor dictating the amount of CPU time necessary for setting up the impedance matrix. Any reduction in processor time needed for the evaluation of $F_A$ and $F_S$ will lower overall requirements for computer resources. Having decided not to employ the point-source approximation (which would be the least time demanding—at the price of reduced accuracy), we define an auxiliary variable $T$ as

$$T = e^{-jk\sqrt{(x_1+x_2)^2+(y_1+y_2)^2+a^2}}$$
$$\frac{1}{\sqrt{(x_1+x_2)^2/2} + [(y_1+y_2)/2]^2 + a^2}$$

(18)

where $x_1$, $x_2$, $y_1$, and $y_2$ are the lower and upper integration limits in (12) and (13). Parameter $a$ is the difference between the $z$ coordinates of the two planar surfaces of interest and, therefore, a constant with respect to the integration. With this notation, $F_S$ can be expressed as

$$F_S = \frac{1}{x_2-x_1} \left[ T \cdot (x_2-x_1)(y_2-y_1) + \int_{x_1}^{x_2} \int_{y_1}^{y_2} T \cdot (x_2-x_1)(y_2-y_1) \right.$$ 
$$\cdot \left( e^{-jk\sqrt{x^2+y^2+a^2}} - T \right) dy'dx' \right].$$

(19)

Similarly, $F_A$—for a falling half rooftop—can be written as

$$F_A = 0.5T \cdot x_2 \cdot 2y_2 + \int_{y_1}^{y_2} \int_{y_1}^{y_2} T \cdot \left( 1 - \frac{x'}{x_2} \right)$$
$$\cdot \left( e^{-jk\sqrt{x'^2+y'^2+a^2}} - T \right) dy'dx'. $$

(20)

The calculation of $F_A$ for a rising half rooftop is analogous.

While [in comparison with (12) and (13)] there are extra additive and subtractive operations in (19) and (20),
the integrands of (19) and (20) are significantly smoother functions than those of (12) and (13) for large values of $\sqrt{x'^2 + y'^2 + a'^2}$. As a result, fewer integration points are needed.

Compared with the point-source approximation, the above procedure costs us some computational time but considerably improves the accuracy of the resulting current coefficients $I_\alpha$ and, therefore, the reliability of the computation.

IV. RESULTS

The calculations presented in this section respect finite conductivities of metals and nonzero conductivities of dielectrics. To prevent computer memory and time requirements from becoming exuberant, however, metallic surfaces were modeled as having zero thicknesses.

The first example is a square patch symmetrically edge fed by a 50-$\Omega$ microstrip transmission line, as shown in the inset of Fig. 4. The structure forms a single element of an array for synthetic aperture radar applications [10]. Although other circuitry (such as feed lines and matching transformers) is integrated on the substrate, it has not been modeled in order to limit the computational space. A minute asymmetry can be observed in both the calculated and measured [11] $E$-plane patterns. Inspection of the calculated current distribution confirms that the asymmetry is a result of the fact that the patch is slightly longer than one half of the guided wavelength at the given frequency. With the exception of angular values below $-80^\circ$ and above $80^\circ$, the calculated and measured patterns are in good agreement.

As a representative of a planar antenna fed by a coaxial probe, we present the arrangement depicted in the inset of Fig. 5(a). Its measured [12] and calculated $E$- and $H$-plane radiation patterns at 6.8 GHz are shown in Fig. 5(a) and (b), respectively. Agreement between calculated and measured patterns is fairly good, especially in the $H$-plane. It is not clear whether the deviations in the $E$-plane are caused by measurement inaccuracies, the inability of our numerical
model to represent circular (rather than square) via holes or a combination of both. (It might also be possible that the measurements in [12] have been conducted at the presence of a larger metallic plate attached to the ground plane.)

Because the patch is fed symmetrically, the cross-polarized component of its $E$-plane radiation pattern should theoretically be zero. In this and the remaining examples, the calculated value is always below $-100$ dB. For the same reason as in the $E$-plane, the $H$-plane cross-polarized component should theoretically be zero at patch’s zenith, i.e., at the angular value of zero degrees. In comparison, the calculated value, once again, is below $-100$ dB. As the test point moves away from zenith, the $H$-plane cross-polarized component increases symmetrically and reaches its maximum at $±90^\circ$.

Fig. 6(a) depicts a rectangular patch capacitively coupled to a coplanar transmission line [13]. $E$- and $H$-plane radiation patterns are shown in Fig. 6(b). The substrate size is assumed to be three times the extent of the patch in both directions.

In order to be able to model the fine features on the back side, nonequidistant segmentation was applied to the structure. Agreement between measurement [13] and computation is generally good. Notice the excellent agreement at $-180^\circ$, i.e., the direction facing the coplanar feed line.

A microstrip antenna composed of parallel dipole resonators of different lengths, aperture-coupled to a microstrip line (as suggested in [1]) is illustrated in Fig. 7. In order to be able to perform a meaningful calculation on available computers, we have modeled the radiating system as a threelayer assemblage only, assuming all metallic surfaces of zero thickness. Refraction occurring at the boundary of dielectrics was properly accounted for by means of Snell’s Law. However, if the ray path (the electrical line of sight) for any two interacting currents was intercepting a metallic surface, mutual impedances for the two currents were set to zero; that is, we assumed that the metallic surfaces provide perfect shielding, i.e., have infinitely high conductivity. These two compromises were the most reasonable arrangement under the limitations of finite virtual memory and computer power. In addition, like in the structure of Fig. 6, a nonequidistant cellular structure was employed.

$E$- and $H$-plane radiation patterns of the entire structure at 5.24 GHz are presented in Fig. 8(a) and (b), respectively. The frequency corresponds to the resonance of the longest pair of dipoles (c.f., Fig. 7). Experimental data [1] are shown to be in good agreement with computed results, especially in the forward direction (angular variable in the range from $-90^\circ$ to $+90^\circ$) with respect to the radiators. We attribute the backward-radiation deviations to the aforementioned compromises that we had to make in the modeling process.

The computation time for this structure was 26 h on a SPARC station 20 with four 100 MHz CPU’s. All other calculations have been performed on an IBM RISC 6000/530 with CPU times ranging from 2 to 24 h.

Note that all examples presented in this paper include the effect of the finite-size substrates and ground planes. A direct comparison between finite and infinite ground planes cannot be conducted with this method due to the limitations in computer resources. From a circuit (not pattern) point of view,
V. CONCLUSIONS

A cellular-space-division-based MoM technique for the analysis of imperfect planar radiators and transmission lines on lossy substrates and finite-extent ground planes is presented. The surface impedances, which are associated with the equivalent surface currents defined on the thin-wall cells, represent their material properties. Dielectric and conductor losses are readily incorporated. Although effects due to radiation are fully included, the surrounding environment need not be modeled as material parameters are defined in relation to a homogeneous medium, e.g., free-space. Performance of the method in terms of radiation patterns of planar radiators is demonstrated at four examples with different feeding mechanisms. Good agreement with measured results is obtained. Aspects of built-in numerical integration techniques are discussed.

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REFERENCES

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